L Number	Hits	Search Text	DB	Time stamp
-	2	5545915.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/21 16:28
-	2	5895951.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/21 16:30
-	2	5879968.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/21 16:52
-	9	("4879254" | "4898835" | "4987098" | "5023191" | "5072266" | "5164327" | "5298442" | "5453390" | "5486715").PN.	USPAT	2003/07/21 16:30
-	4	("4430792" | "4503598" | "4567641" | "4598461").PN.	USPAT	2003/07/21 16:48
-	2	4879254.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/21 16:52
-	4	("4430792" | "4503598" | "4567641" | "4598461").PN.	USPAT	2003/07/21 16:53
-	57	4879254.URPN.	USPAT	2003/12/17 18:21
-	14	("4231811" | "4502069" | "4516143" | "4598461" | "4853345" | "4879254" | "4920064" | "4985740" | "5034336" | "5155052" | "5173435" | "5302537" | "5731604" | "5795793").PN.	USPAT	2003/07/21 17:04
-	0	jp-215025-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/22 17:12
-	0	jp-9215025-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/22 17:12
-	58	4879254.URPN.	USPAT	2003/12/17 18:19
-	58	4879254.URPN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/17 18:22
-	52	4879254.URPN. and (@ad<19970808 or @rlad<19970808)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/17 18:23
-	0	5910668.URPN.	USPAT	2003/12/17 18:30
-	0	5910668.URPN.	USPAT	2003/12/17 18:30
-	11	("4853345" | "4879254" | "4960723" | "5079602" | "5155052" | "5178370" | "5179032" | "5262336" | "5366914" | "5451531" | "5731604").PN.	USPAT	2003/12/17 18:30
-	2	5631484.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/21 17:03
-	27	5631484.URPN.	USPAT	2004/06/21 16:29
-	19412	power with mosfet	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 14:59
-	218	(power with mosfet) with planar	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/21 17:04

–	88	((power with mosfet) with planar) and (sidewall or (side adj wall))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/21 17:06
–	19	(((power with mosfet) with planar) and (sidewall or (side adj wall))) and (@ad<19970808 or @rlad<19970808)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:01
–	7828	power adj mosfet	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:00
–	181	(power adj mosfet) with planar	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:00
–	59	((power adj mosfet) with planar) and (@ad<19970808 or @rlad<19970808)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:06
–	384	(power adj mosfet) and (sidewall or (side adj wall)) and (@ad<19970808 or @rlad<19970808)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:08
–	237	((power adj mosfet) and (sidewall or (side adj wall)) and (@ad<19970808 or @rlad<19970808)) and implant$5 and etch$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/23 15:08

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